

Microstrip Analysis on OSH Park's 4-Layer Stackup using HFSS

Comparing unmasked and masked microstrip analysis given by OSH Park's specifications and FR408 datasheet, and by [Harmon Instruments](#)' measurements. Ansys Electromagnetics Suite v19.1 was used.

OSH Park 4 Layer Stackup (layers 1 & 2):

1 mil (0.0254 mm)	Solder mask
1.4 mil (0.0356 mm)	1 oz copper
6.7 mil (0.1702 mm)	FR408 prepreg (Er = 3.66, Loss Tan. = 0.012 @ 1GHz)
0.7 mil (0.0178 mm)	0.5 oz copper
47 mil (1.1938 mm)	FR408 core

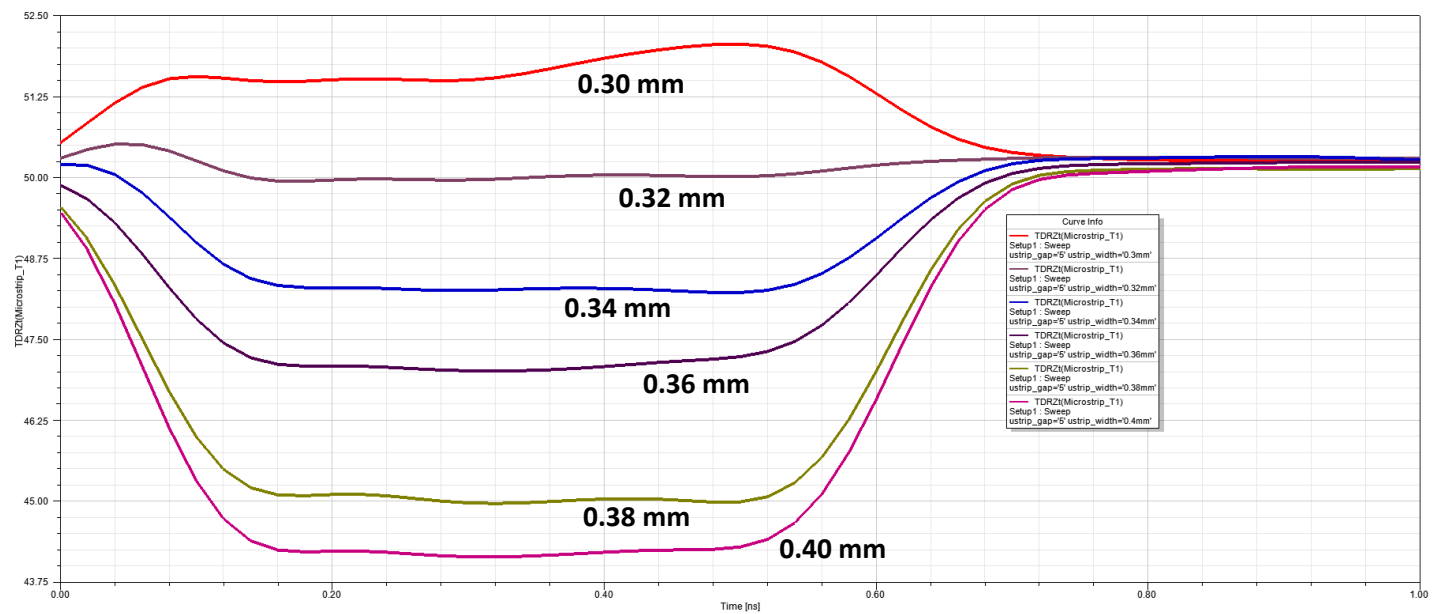
Microstrip Board Dimensions:

50 mm	PCB Length
16 mm	PCB Width
5x prepreg	Microstrip Gap
0.35 mm / 5 mm x 10	Via Diameter / Spacing

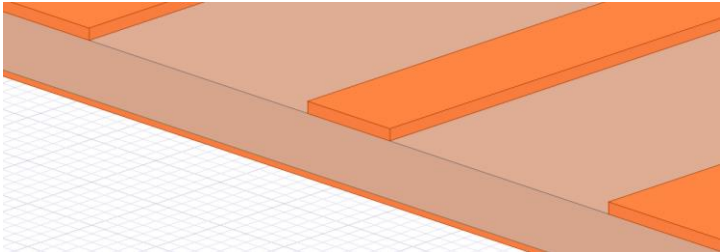
HFSS Solution and Sweep Setup (default except for below):

Terminal with Wave Ports	Solution Type
1.265 GHz	Solution Frequency
40	Max # of Passes
0.01	Maximum Delta S
1%	Maximum Delta Zo
Interpolating Linear Step	Sweep Type
100 MHz / 10 GHz / 25 MHz	Sweep Start, End, Step
1000	Sweep Max Solutions

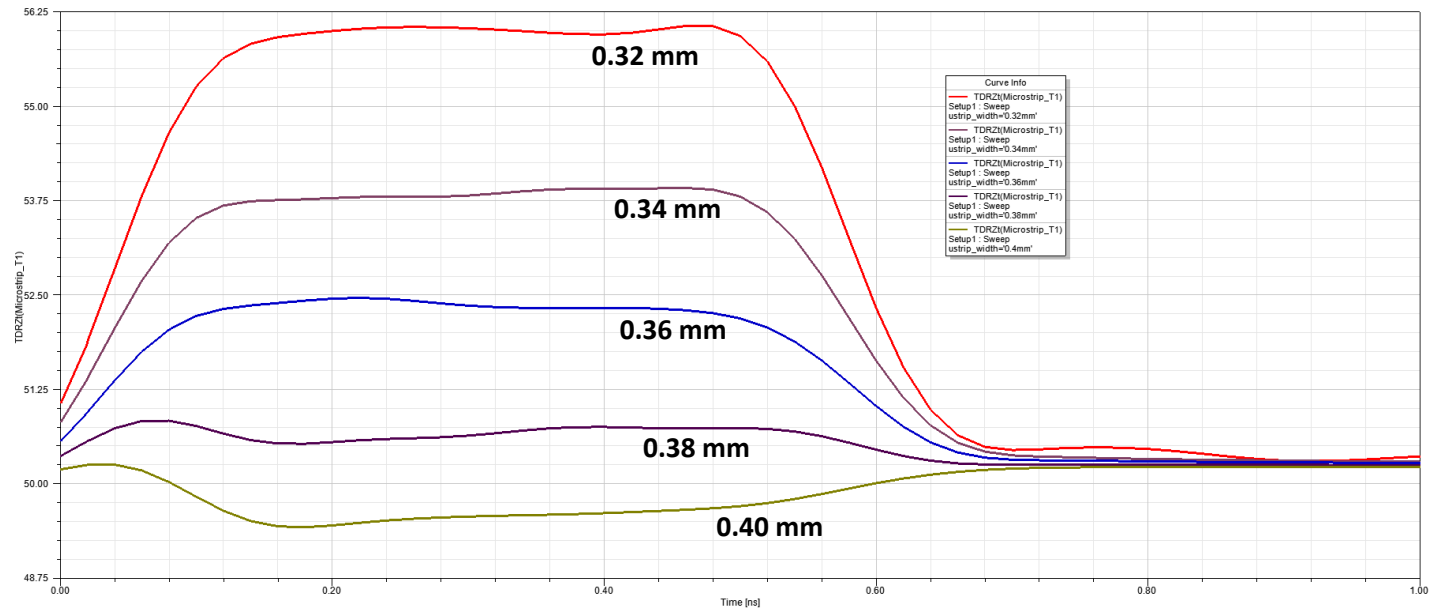
Unmasked Microstrip TDR Plot (parametric sweep of microstrip width w/ datasheet spec):



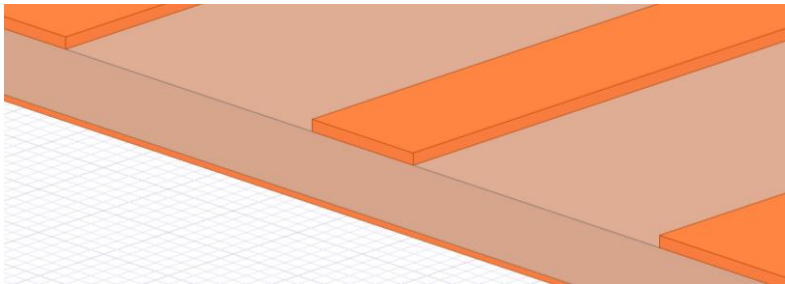
0.17 mm	FR408 prepreg (Er = 3.66)
0.32 mm	50Ω Microstrip width



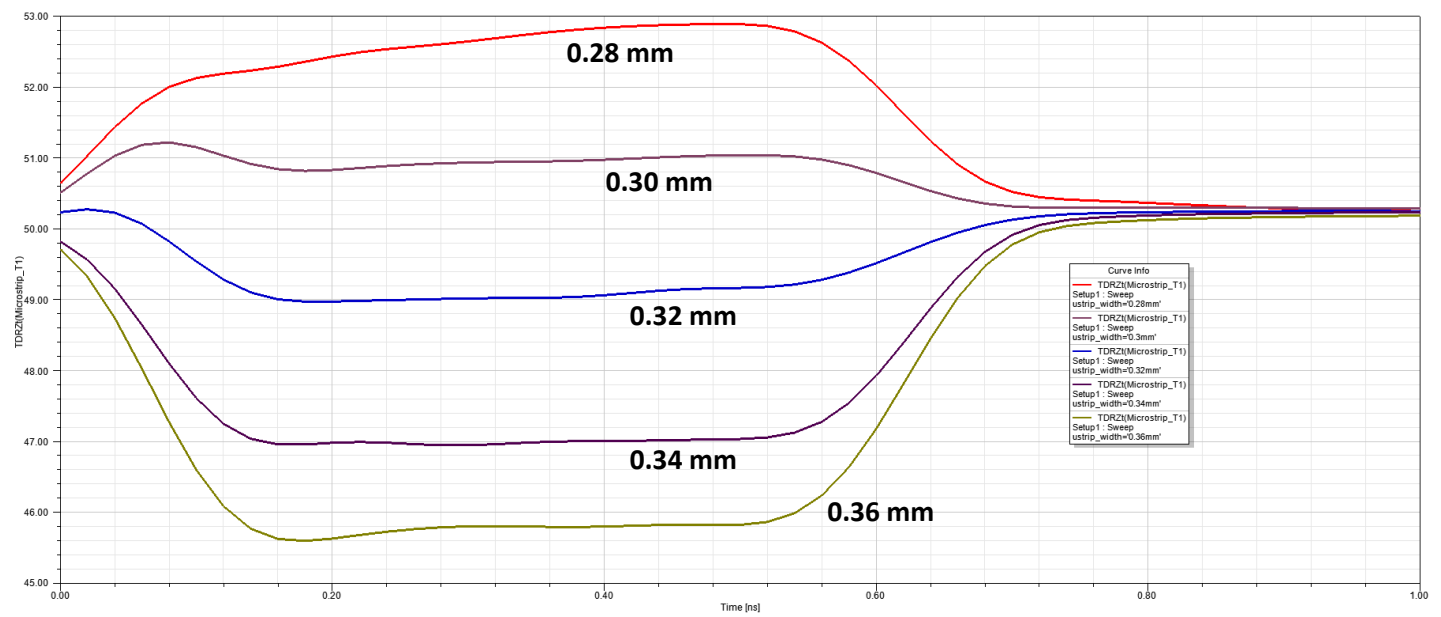
Unmasked Microstrip TDR Plot (parametric sweep of microstrip width w/ [Harmon Instruments](#) spec):



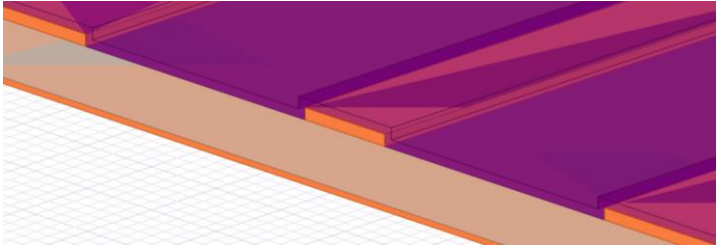
0.19 mm	FR408 prepreg (Er = 3.30)
0.39 mm	50Ω Microstrip width



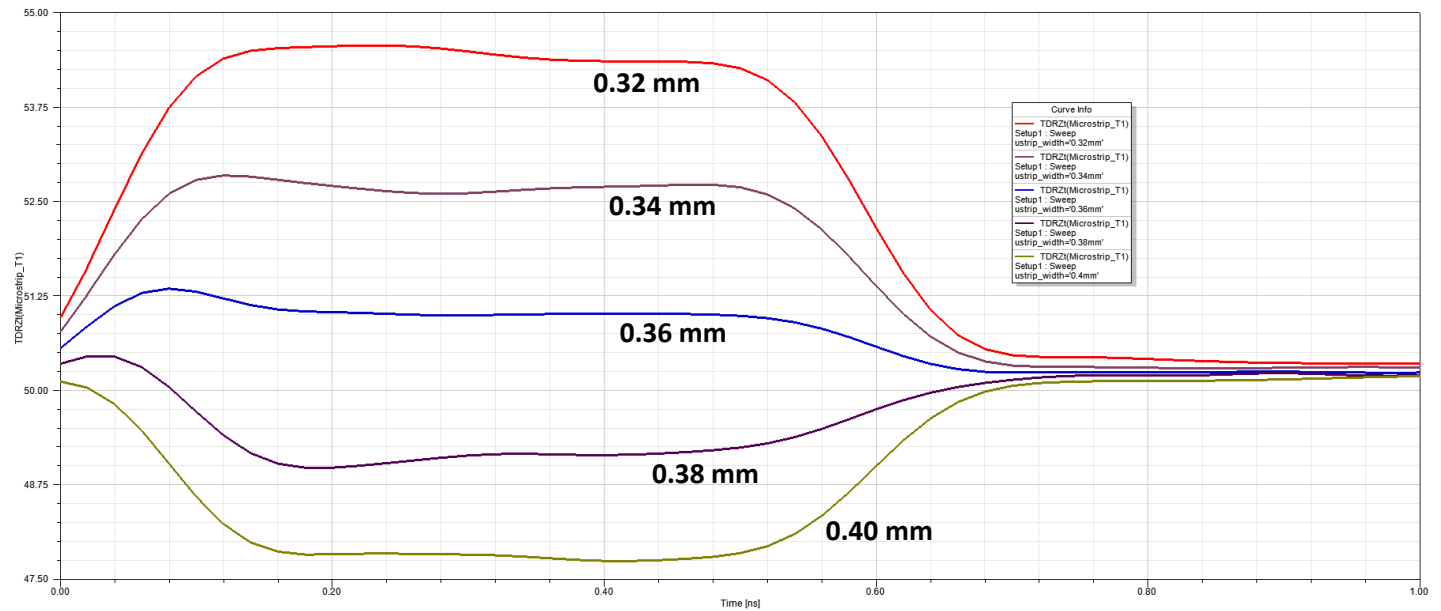
Masked Microstrip TDR Plot (parametric sweep of microstrip width w/ datasheet spec):



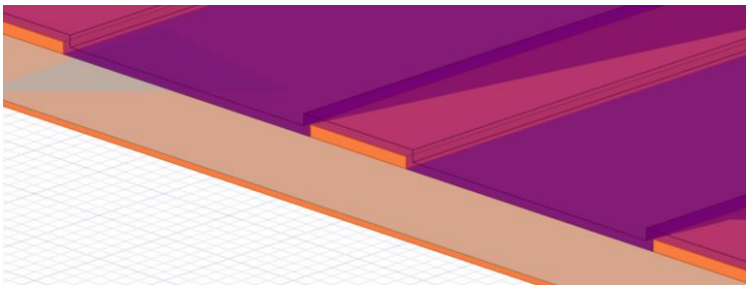
0.17 mm	FR408 prepreg (Er = 3.66)
0.31 mm	50Ω Microstrip width



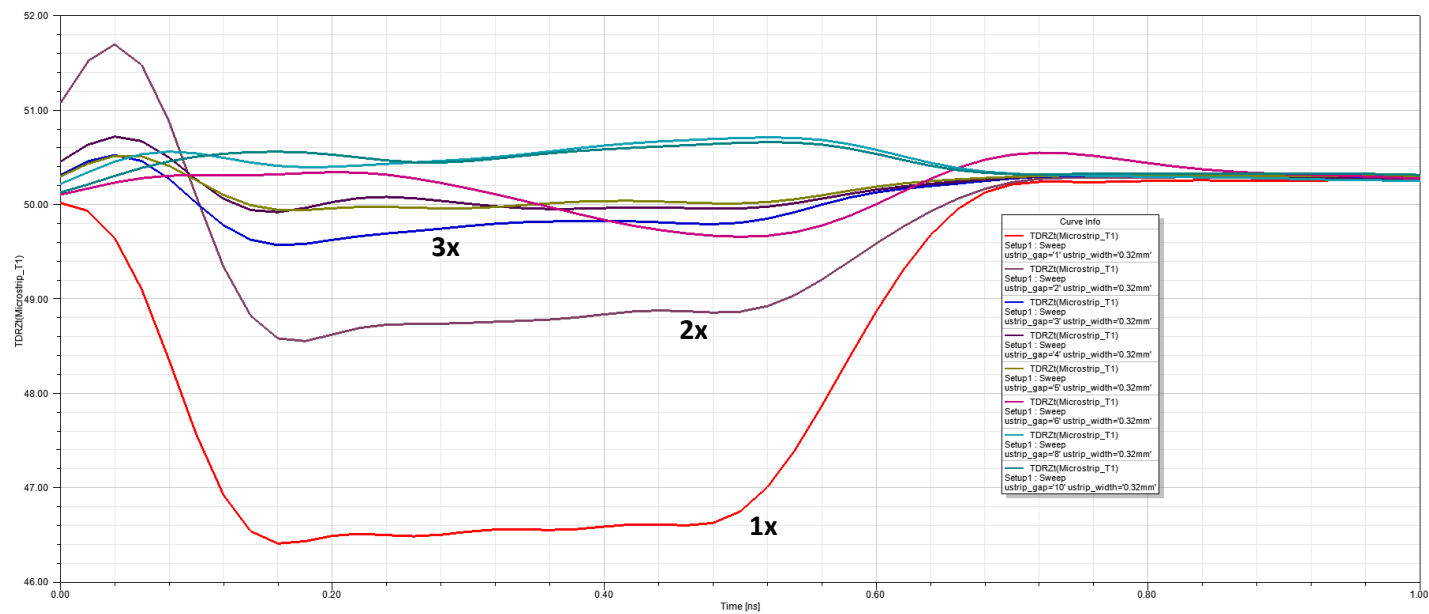
Masked Microstrip TDR Plot (parametric sweep of microstrip width w/ [Harmon Instruments](#) spec):



0.19 mm	FR408 prepreg (Er = 3.30)
0.37 mm	50Ω Microstrip width



Unmasked Microstrip TDR Plot (parametric sweep of microstrip gap – multiple of prepreg height):



0.17 mm	FR408 prepreg (Er = 3.66)
0.32 mm	50Ω Microstrip width
≥ 4x prepreg	Microstrip Gap